

V1.0.0

GaAs QFN 4x4mm Low Noise Amplifier 1-12GHz

Features

• Single Biasing Voltage (Self Biased)

• Frequency: 1-12GHz

Small Signal Gain: 17dB Typical
 Gain Flatness: ±0.75dB Typical
 Noise Figure:1.4dB Typical

P1dB: 19dBm Typical
Power Supply: +5V/40mA
Input/Output: 50Ω

• Package Size: 4 x 4x 0.8mm

Typical Applications

• Test Instrumentation

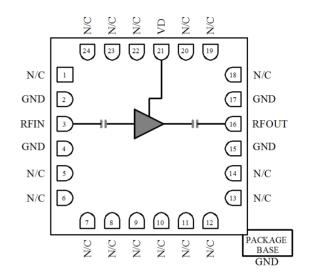
Microwave Radio & VSAT

Military & Space

Telecom Infrastructure

Fiber Optics

Functional Block Diagram



Electrical Specifications

TA = +25°C, VD = +5V, IDD = 40mA Typical

Parameters	Min.	Тур.	Max.	Units
Frequency	1		12	GHz
Small Signal Gain	15	17		dB
Gain Flatness		±0.75		dB
Noise Figure		1.4		dB
P1dB - Output 1dB Compression	18	19		dBm
Psat - Saturated Output Power		20		dBm
OIP3 - Output Third Order Intercept		28		dBm
Input Return Loss		-12		dB
Output Return Loss		-13		dB

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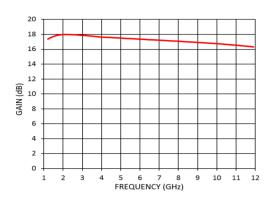
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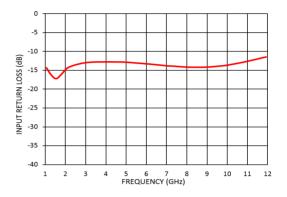


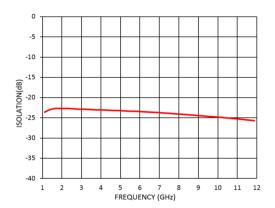
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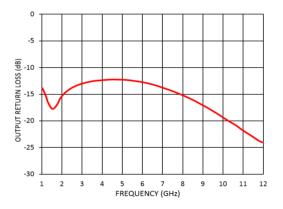
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Measurement Plots: S-parameters

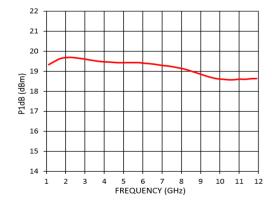




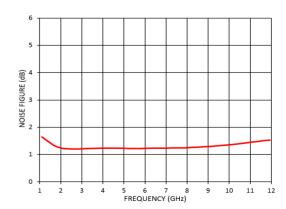




Measurement Plots: P1dB



Measurement Plots: Noise Figure



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Absolute Maximum Ratings

Drain Bias Voltage (VD)	+7V	
RF Input Power (RFIN)(VD=+5V)	+20dBm	
Channel Temperature	175°C	
Continuous Pdiss (T = 85 °C) (derate 3.5mW/°C above 85 °C)	0.32W	
Thermal Resistance (channel to die bottom)	50°C/W	
Operating Temperature	-55°C to +85 °C	
Storage Temperature	-55°C to +150 °C	

Typical Supply Current vs. VD

VD (V)	IDD (mA)	
+5	40	



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

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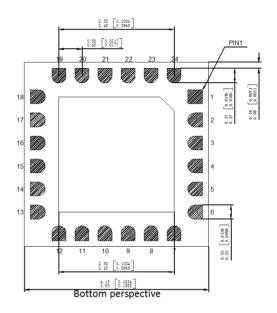
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Outline Drawing:

All Dimensions in mm[inches]





28	1	
0.0362		
0.92		

Notes:

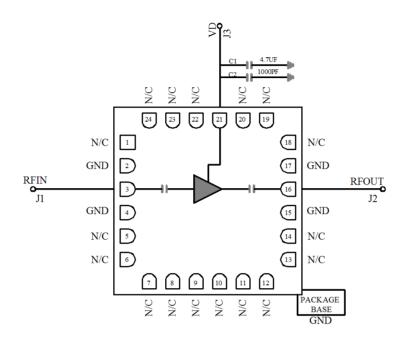
- 1. Package body material : Alumina.
- 2. Lead and ground paddle plating: Gold flash over nickel.
- 3. Dimensions are in millimeters(inches).
- 4. Lead spacing tolerance is non-cumulative.



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Assembly Drawing

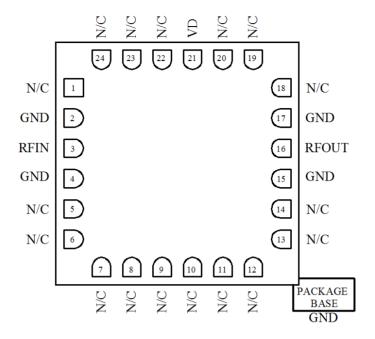


Pin Descriptions

No	Function	Description
1,5,6,7,8,9,10,11,12,13, 14,18,19,20,22,23,24	NC	No connection. These pins may be connected to RF ground. Performance will not be affected.
3	RF IN	RF Signal Input. This pad is ac-coupled and matched to 50 Ω .
16	RF OUT	RF Signal Output. This pad is ac-coupled and matched to 50 Ω .
21	VD	Connect to external 1000pf and 4.7uf bypass capacitors.
2,4,15,17	GND	These pins & exposed ground paddle must be connected to RF/DC ground
	GND	Package bottom must be connected to RF/DC ground



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Biasing and Operation

Turn ON procedure:

- 1. Connect GND to RF and dc ground.
- 2. Apply positive drain voltage VD and set to +5.0 V.
- 3. Apply RF signal.

Turn OFF procedure:

- 1. Turn off the RF signal.
- 2. Turn off the positive drain voltage VD.

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